

Standard series

Series/Type:

Date: November 2010

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Standard series

<u>SMD</u>

Features

- ESD protection to IEC 61000-4-2, level 4
- Bidirectional ESD protection in one component
- No change in ESD protection performance at temperatures up to 85 °C (temperature derating)
- Use of parasitic capacitance for EMI suppression and high-frequency filtering (replacement of additional MLCC)
- High surge current capability
- Low parasitic inductance
- Low leakage current
- Fast response time <0.5 ns</p>
- Lead-free nickel barrier terminations suitable for lead-free soldering
- RoHS-compatible

Applications

- Interfaces, data lines, power lines and audio lines, pushbuttons, serial ports, ICs and I/O ports
- Consumer electronic products (TV, DVD player/recorder, set-top box, game consoles, MP3 player, digital still/video camera, etc.)
- EDP products (desktop and notebook computer, monitor, PDA, printer, memory card, control unit, head set, speaker, HDD, optical drive, etc.)
- Industrial applications

Design

- Multilayer technology
- Nickel barrier termination (Ag/Ni/Sn) for lead-free soldering

Marking

Due to the symmetrical configuration no marking information is needed.

General technical data

Maximum DC operating voltage		V _{DC,max}	5.6 22	V
Typical capacitance		C _{typ}	15 470	pF
Air discharge ESD capability	to IEC 61000-4-2	V _{ESD,air}	15	kV
Contact discharge ESD capability	to IEC 61000-4-2	V _{ESD,contact}	8	kV
Leakage current ¹⁾	$(V_{leak} = 5.6 V)$	I _{leak}	1	μA
Operating temperature	(without derating)	T _{op}	-40/+85	°C
Storage temperature		LCT/UCT	-40/+125	°C

Single chip



4-fold array



1) Except CDS2C05GTA and CDS3C05GTA V_{leak} = 3.3 V. Any operating voltage lower than V_{leak} results in lower leakage current.



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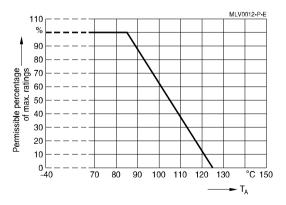
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Electrical specifications and ordering codes

Maximum ratings (T_{op,max} = 85 °C) and characteristics (T_A = 25 °C)

Туре	Ordering code	$V_{\text{DC,max}}$	$V_{\text{BR,min}}$	V _{clamp,max}	I _{PP}	P _{PP}	C _{typ}
7 1 ² -	J		(1 mA)		(8/20 µs)	(8/20 µs)	
		V	V	V	A	W	pF
Array, 4-fold, 050	8, no semiconductor	diode e	quivaler	nt			
CDA4C20GTA	B72714D0200A060	22	24	60	10	600	33
Array, 4-fold, 061	2, no semiconductor	diode e	quivaler	nt			
CDA5C20GTA	B72724D0200A062	22	25	50	30	2200	56
Single, 0201, no	semiconductor diode	equival	ent				
CDS1C05GTA	B72440D0050A060	5.6	12	39	-	-	15
Single, 0402, SO	D-723						
CDS2C05GTA	B72590D0050A060	5.6	6.4	24	10	320	180 ¹⁾
CDS2C15GTA	B72590D0150A060	15	20	46	10	670	47
Single, 0603, SO	D-523						
CDS3C05GTA	B72500D0050A060	5.6	6.4	19	30	1000	470 ¹⁾
CDS3C09GTA	B72500D0090A060	9	10	30	30	1600	220 ¹⁾
CDS3C15GTA	B72500D0150A060	15	22	42	30	2000	160 ¹⁾
CDS3C20GTA	B72500D0200A060	22	25	50	30	2200	56
Single, 1003, SO	D-323						
CDS4C12GTA	B72570D0120A060	12	16	46	20	1000	82

Typical characteristics



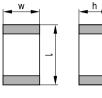


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Dimensional drawings

Single device

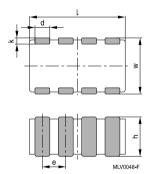




Dimensions in mm

Case	(inch)	0201		0402		0603		1003		
size	(mm)	0603	0603		1005		1608		2508	
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
I		0.57	0.63	0.85	1.15	1.45	1.75	2.34	2.74	
w		0.27	0.33	0.4	0.6	0.7	0.9	0.7	0.9	
h		0.27	0.33	0.4	0.6	0.7	0.9	0.7	0.9	
k		0.1	0.2	0.1	0.3	0.1	0.4	0.13	0.75	

Array device



Dimensions in mm

Case size	(inch) (mm)	0508 1220		0612 1632	
		Min.	Max.	Min.	Max.
I		1.8	2.2	3.0	3.4
w		1.05	1.45	1.45	1.75
h		-	0.9	-	0.9
d		0.2	0.4	0.25	0.55
е		0.4	0.6	0.61	0.91
k		-	0.35	-	0.35

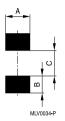


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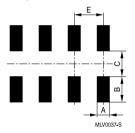
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Recommended solder pads

Single device



Array device



Dimensions in mm

Case size	(inch)	0201	0402	0603	1003
	(mm)	0603	1005	1608	2508
A		0.3	0.6	1.0	0.8
В		0.25	0.6	1.0	0.8
С		0.3	0.5	1.0	1.45

Dimensions in mm

(inch)	0508	0612
(mm)	1220	1632
	0.35	0.5
	0.9	0.7
	0.4	1.2
	0.5	0.76
	· · ·	(mm) 1220 0.35 0.9 0.4



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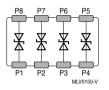
Pin configurations

Single device



Pin	Description
P1	GND
P2	I/O line

Array device



Pin	Description
P1	GND
P2	GND
P3	GND
P4	GND
P5	I/O line 1
P6	I/O line 2
P7	I/O line 3
P8	I/O line 4

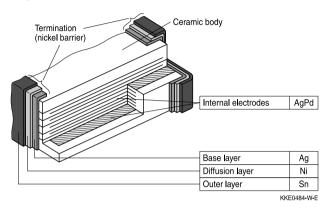


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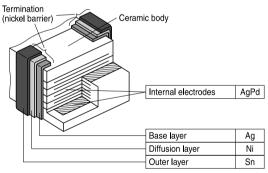
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Termination

Single device



Array device



KKE0366-S-E



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Delivery mode

EIA case size	Taping	Reel size	Packing unit	Туре	Ordering code
		mm	pcs.		
0201	Cardboard	180	15000	CDS1C05GTA	B72440D0050A060
0402	Cardboard	180	10000	CDS2C05GTA	B72590D0050A060
0402	Cardboard	180	10000	CDS2C15GTA	B72590D0150A060
0508	Cardboard	180	4000	CDA4C20GTA	B72714D0200A060
0603	Cardboard	180	4000	CDS3C05GTA	B72500D0050A060
0603	Cardboard	180	4000	CDS3C09GTA	B72500D0090A060
0603	Cardboard	180	4000	CDS3C15GTA	B72500D0150A060
0603	Cardboard	180	4000	CDS3C20GTA	B72500D0200A060
0612	Blister	180	3000	CDA5C20GTA	B72724D0200A062
1003	Cardboard	180	4000	CDS4C12GTA	B72570D0120A060

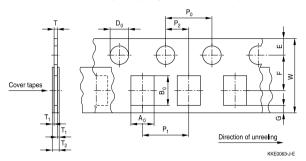


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1 Taping and packing for chip and array CeraDiodes

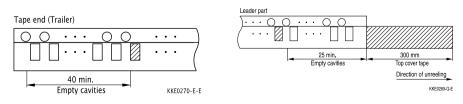
1.1 Cardboard tape (taping to IEC 60286-3)



Dimensions in mm

Case size (inch)		0201	0402	0603	1003	0508	Tolerance
(mm)		0603	1005	1608	2508	1220	
Compartment width	A ₀	0.38 ±0.05	0.6	0.95	1.0	1.6	±0.2
Compartment length	B ₀	0.68 ±0.05	1.15	1.8	2.85	2.4	±0.2
Sprocket hole diameter	D ₀	1.5 ±0.1	1.5	1.5	1.5	1.5	+0.1/ -0
Sprocket hole pitch	P ₀	$4.0 \pm 0.1^{1)}$	4.0	4.0	4.0	4.0	±0.1 ¹⁾
Distance center hole to center	P ₂	2.0 ± 0.05	2.0	2.0	2.0	2.0	±0.05
compartment							
Pitch of component compartments	P ₁	2.0 ± 0.05	2.0	4.0	4.0	4.0	±0.1
Tape width	W	8.0 ±0.3	8.0	8.0	8.0	8.0	±0.3
Distance edge to center of hole	Е	1.75 ±0.1	1.75	1.75	1.75	1.75	±0.1
Distance center hole to center	F	3.5 ± 0.05	3.5	3.5	3.5	3.5	±0.05
compartment							
Distance compartment to edge	G	1.35 min.	0.75	0.75	0.75	0.75	min.
Thickness tape	Т	0.35 ±0.02	0.6	0.9	1.0	0.95	max.
Overall thickness	T ₂	0.4 min.	0.7	1.1	1.1	1.12	max.

 $^{1)} \le \pm 0.2$ mm over 10 sprocket holes

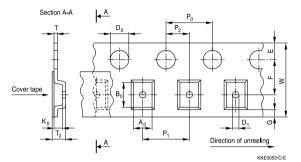




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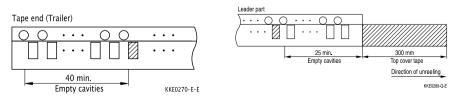
1.2 Blister tape (taping to IEC 60286-3)



Dimensions in mm

Case size (inch)		0506	0612	1012	Tolerance
(mm)		1216	1632	2532	
Compartment width	A ₀	1.5	1.9	2.8	±0.2
Compartment length	B ₀	1.8	3.5	3.5	±0.2
Compartment height	K ₀	0.8	1.8	1.8	max.
Sprocket hole diameter	D ₀	1.5	1.5	1.5	+0.1/ -0
Compartment hole diameter	D ₁	1.0	1.0	1.0	min.
Sprocket hole pitch	P ₀	4.0	4.0	4.0	±0.11)
Distance center hole to center	P_2	2.0	2.0	2.0	±0.05
compartment					
Pitch of component compartments	P ₁	4.0	4.0	4.0	±0.1
Tape width	W	8.0	8.0	8.0	±0.3
Distance edge to center of hole	Е	1.75	1.75	1.75	±0.1
Distance center hole to center	F	3.5	3.5	3.5	±0.05
compartment					
Distance compartment to edge	G	0.75	0.75	0.75	min.
Thickness tape	Т	0.3	0.3	0.3	max.
Overall thickness	T ₂	1.3	2.5	2.5	max.

 $^{1)} \leq \pm 0.2 \text{ mm}$ over 10 sprocket holes

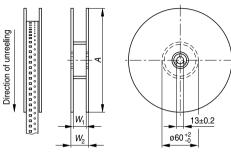




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1.3 Reel packing



KKE0058-I-E

Dimensions in mm

		Dimensions	Tolerance	Dimensions	Tolerance
Reel diameter	А	180	+0/ -3	330	±2
Reel width (inside)	W ₁	8.4	+1.5/ -0	8.4	+1.5/ -0
Reel width (outside)	W ₂	14.4	max.	14.4	max.

Package: 8-mm tape Reel material: Plastic

1.4 Packing units

Case size	Ø 180-mm reel	Ø 330-mm reel	Таре
(inch) / (mm)	pieces	pieces	
0201 / 0603	15000	-	cardboard
0402 / 1005	10000	50000	cardboard
0603 / 1608	4000	16000	cardboard
1003 / 2508	4000	16000	cardboard
0506 / 1216	3000	12000	blister
0508 / 1220	4000	16000	cardboard
0612 / 1632	3000	12000	blister
1012 / 2532	2000	8000	blister



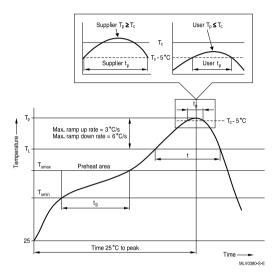
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Soldering directions

1 Reflow soldering temperature profile

Recommended temperature characteristic for reflow soldering following JEDEC J-STD-020D



Profile feature		Sn-Pb eutectic assembly	Pb-free assembly	
Preheat and soak				
- Temperature min	T _{smin}	100 °C	150 °C	
- Temperature max	T _{smax}	150 °C	200 °C	
- Time	$t_{\text{smin}} \text{ to } t_{\text{smax}}$	60 120 s	60 180 s	
Average ramp-up rate	T _{smax} to T _p	3 °C/ s max.	3 °C/ s max.	
Liquidous temperature	TL	183 °C	217 °C	
Time at liquidous	tL	60 150 s	60 150 s	
Peak package body temperature	T _p ¹⁾	220 °C 235 °C ²⁾	245 °C 260 °C ²⁾	
Time (t _P) ³⁾ within 5 °C of specified		20 s ³⁾	30 s ³⁾	
classification temperature (T_c)		20.5%	30.5%	
Average ramp-down rate	T_p to T_{smax}	6 °C/ s max.	6 °C/ s max.	
Time 25 °C to peak temperature		maximum 6 min	maximum 8 min	

1) Tolerance for peak profile temperature (T_P) is defined as a supplier minimum and a user maximum.

2) Depending on package thickness. For details please refer to JEDEC J-STD-020D.

3) Tolerance for time at peak profile temperature (t_P) is defined as a supplier minimum and a user maximum.

Note: All temperatures refer to topside of the package, measured on the package body surface. Number of reflow cycles: 3



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2 Soldering guidelines

The use of mild, non-activated fluxes for soldering is recommended, as well as proper cleaning of the PCB.

The components are suitable for reflow soldering to JEDEC J-STD-020D.

3 Solder joint profiles / solder quantity

3.1 Cement quantity

The component is fixed onto the circuit board with cement prior to soldering. It must still be able to move slightly. When the board is placed into the reflow oven, excessively rigid fixing can lead to high forces acting on the component and thus to a break. In addition, too much cement can lead to unsymmetrical stressing and thus to mechanical fracture of the component. The cement must also be so soft during mounting that no mechanical stressing occurs.

3.2 Mounting the components on the board

It is best to mount the components on the board before soldering so that one termination does not enter the oven first and the second termination is soldered subsequently. The ideal case is simultaneous wetting of both terminations.

3.3 Solder joint profiles

If the meniscus height is too low, that means the solder quantity is too low, the solder joint may break, i.e. the component becomes detached from the joint. This problem is sometimes interpreted as leaching of the external terminations.

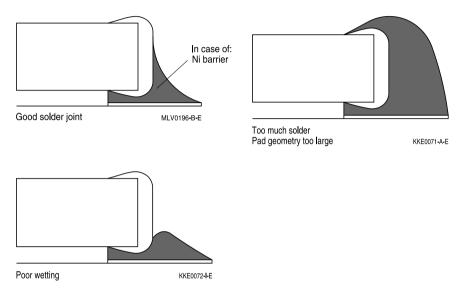
If the solder meniscus is too high, i.e. the solder quantity is too large, the vise effect may occur. As the solder cools down, the solder contracts in the direction of the component. If there is too much solder on the component, it has no leeway to evade the stress and may break, as in a vise.





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3.3.1 Solder joint profiles for nickel barrier termination



Good and poor solder joints caused by amount of solder in infrared reflow soldering



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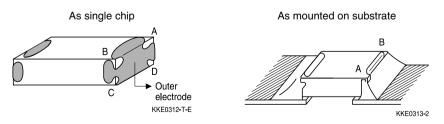
4 Solderability tests

Test	Standard	Test conditions / Sn-Pb soldering	Test conditions / Pb-free soldering	Criteria / test results
Wettability	IEC 60068-2-58	Immersion in 60/40 SnPb solder using non-activated flux at 215 ±3 °C for 3 ±0.3 s	Immersion in Sn96.5Ag3.0Cu0.5 solder using non- or low activated flux at 245 \pm 5 °C for 3 \pm 0.3 s	Covering of 95% of end termination, checked by visual inspection
Leaching resistance	IEC 60068-2-58	Immersion in 60/40 SnPb solder using mildly activated flux without preheating at 255 ±5 °C for 10 ±1 s	Immersion in Sn96.5Ag3.0Cu0.5 solder using non- or low activated flux without preheating at 255 ±5 °C for 10 ±1 s	No leaching of contacts
Tests of resistance to soldering heat for SMDs	IEC 60068-2-58	Immersion in 60/40 SnPb for 10 s at 260 °C	Immersion in Sn96.5Ag3.0Cu0.5 for 10 s at 260 °C	Capacitance change: −15% ≤∆C ≤15%

Note:

Leaching of the termination

Effective area at the termination might be lost if the soldering temperature and/or immersion time are not kept within the recommended conditions. Leaching of the outer electrode should not exceed 25% of the chip end area (full length of the edge A-B-C-D) and 25% of the length A-B, shown below as mounted on the substrate.





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5 Notes for proper soldering

5.1 Preheating and cooling

- The average ramp-up rate must not exceed 3 °C/s.
- The cooling rate must not exceed 8 °C/s.

5.2 Repair / rework

Manual soldering with a soldering iron must be avoided, hot-air methods are recommended for making repairs.

5.3 Cleaning

All environmentally compatible agents are suitable for cleaning. Select the appropriate cleaning solution according to the type of flux used. The temperature difference between the components and cleaning liquid must not be greater than 100 °C. Ultrasonic cleaning should be carried out with the utmost caution. Too high ultrasonic power can impair the adhesive strength of the metal-lized surfaces. Insufficient or excessive cleaning can be detrimental to CeraDiode performance.

5.4 Solder paste printing (reflow soldering)

An excessive application of solder paste results in too high a solder fillet, thus making the chip more susceptible to mechanical and thermal stress. This will lead to the formation of cracks. Too little solder paste reduces the adhesive strength on the outer electrodes and thus weakens the bonding to the PCB. The solder should be applied smoothly to the end surface to a height of min. 0.2 mm.

5.5 Selection of flux

Used flux should have less than or equal to 0.1 wt % of halogenated content, since flux residue after soldering could lead to corrosion of the termination and/or increased leakage current on the surface of the CeraDiode. Strong acidic flux must not be used. The amount of flux applied should be carefully controlled, since an excess may generate flux gas, which in turn is detrimental to sol-derability.

5.6 Storage

Solderability is guaranteed for one year from date of delivery, provided that components are stored in their original packages.

Storage temperature:-25 °C to +45 °CRelative humidity:≤75% annual average, ≤95% on 30 days a year

The solderability of the external electrodes may deteriorate if SMDs are stored where they are exposed to high humidity, dust or harmful gas (hydrogen chloride, sulfurous acid gas or hydrogen sulfide).

Do not store SMDs where they are exposed to heat or direct sunlight. Otherwise the packing material may be deformed or SMDs may stick together, causing problems during mounting.

After opening the factory seals, such as polyvinyl-sealed packages, it is recommended to use the SMDs as soon as possible.



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5.7 Placement of components on circuit board

It is of advantage to place the components on the board before soldering so that their two terminals do not enter the solder oven at different times. Ideally, both terminals should be wetted simultaneously.

5.8 Soldering caution

- Sudden heating or cooling of the component results in thermal destruction by cracks.
- An excessively long soldering time or high soldering temperature results in leaching of the outer electrodes, causing poor adhesion due to loss of contact between electrodes and termination.
- Avoid manual soldering with a soldering iron.
- Wave soldering must not be applied for CeraDiodes designated for reflow soldering only.
- Keep to the recommended down-cooling rate.

5.9 Standards

CECC 00802 IEC 60068-2-58 IEC 60068-2-20 JEDEC J-STD-020D



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Symbols and terms

CeraDiode	Semiconductor diode	
C _{max}		Maximum capacitance
C _{typ}		Typical capacitance
I _{BR}	I _R , I _T	(Reverse) current @ breakdown voltage
I _{leak}	I _{RM}	(Reverse) leakage current
I _{PP}	I _{PP}	Current @ clamping voltage
I _{PP}	I_{P}, I_{PP}	Peak pulse current
P _{PP}	P _{PP}	Peak pulse power
T _{op}		Operating temperature
T _{stg}		Storage temperature
V _{BR}	V _{BR}	(Reverse) breakdown voltage
V _{BR,min}		Minimum breakdown voltage
V _{clamp}	$V_{cl,} V_{C}$	Clamping voltage
V _{clamp,max}		Maximum clamping voltage
V _{DC}	$V_{\text{RM}},V_{\text{RWM}},V_{\text{WM}},V_{\text{DC}}$	(Reverse) stand-off voltage, working
		voltage, operating voltage
V _{DC,max}		Maximum DC operating voltage
V _{ESD,air}		Air discharge ESD capability
V _{ESD,contact}		Contact discharge ESD capability
V _{leak}	$V_{RM},V_{RWM},V_{WM},V_{DC}$	(Reverse) voltage @ leakage current
- *)	I _F	Current @ forward voltage
- *)	I _{RM} , I _{RM,max} @V _{RM}	(Reverse) current @ maximum reverse
		stand-off voltage, working voltage,
		operating voltage
- *)	V _F	Forward voltage

*) Not applicable due to bidirectional characteristics of CeraDiodes



Cautions and warnings

General

Some parts of this publication contain statements about the suitability of our CeraDiodes for certain areas of application, including recommendations about incorporation/design-in of these products into customer applications. The statements are based on our knowledge of typical requirements often made of our CeraDiodes in the particular areas. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our CeraDiodes for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always incumbent on the customer to check and decide whether the CeraDiodes with the properties described in the product specification are suitable for use in a particular customer application.

- Do not use EPCOS CeraDiodes for purposes not identified in our specifications, application notes and data books.
- Ensure the suitability of a CeraDiode in particular by testing it for reliability during design-in. Always evaluate a CeraDiode under worst-case conditions.
- Pay special attention to the reliability of CeraDiodes intended for use in safety-critical applications (e.g. medical equipment, automotive, spacecraft, nuclear power plant).

Design notes

- Always connect a CeraDiode in parallel with the electronic circuit to be protected.
- Consider maximum rated power dissipation if a CeraDiode has insufficient time to cool down between a number of pulses occurring within a specified isolated time period. Ensure that electrical characteristics do not degrade.
- Consider derating at higher operating temperatures. Choose the highest voltage class compatible with derating at higher temperatures.
- Surge currents beyond specified values will puncture a CeraDiode. In extreme cases a CeraDiode will burst.
- If steep surge current edges are to be expected, make sure your design is as low-inductance as possible.
- In some cases the malfunctioning of passive electronic components or failure before the end of their service life cannot be completely ruled out in the current state of the art, even if they are operated as specified. Do not use CeraDiodes in applications requiring a very high level of operational safety and especially when the malfunction or failure of a passive electronic component could endanger human life or health (e.g. in accident prevention, life-saving systems, or automotive battery line applications such as clamp 30), ensure by suitable design of the application or other measures (e.g. installation of protective circuitry or redundancy) that no injury or damage is sustained by third parties in the event of such a malfunction or failure.
- Specified values only apply to CeraDiodes that have not been subject to prior electrical, mechanical or thermal damage. The use of CeraDiodes in line-to-ground applications is therefore not advisable, and it is only allowed together with safety countermeasures like thermal fuses.

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Storage

- Only store CeraDiodes in their original packaging. Do not open the package before storage.
- Storage conditions in original packaging: temperature -25 to +45°C, relative humidity ≤75% annual average, maximum 95%, dew precipitation is inadmissible.
- Do not store CeraDiodes where they are exposed to heat or direct sunlight. Otherwise the packaging material may be deformed or CeraDiodes may stick together, causing problems during mounting.
- Avoid contamination of the CeraDiode surface during storage, handling and processing.
- Avoid storing CeraDiodes in harmful environments where they are exposed to corrosive gases for example (SO_x, Cl).
- Use CeraDiodes as soon as possible after opening factory seals such as polyvinyl-sealed packages.
- Solder CeraDiodes after shipment from EPCOS within the time specified: 12 months.

Handling

- Do not drop CeraDiodes and allow them to be chipped.
- Do not touch CeraDiodes with your bare hands gloves are recommended.
- Avoid contamination of the CeraDiode surface during handling.

Mounting

- When CeraDiodes are encapsulated with sealing material or overmolded with plastic material, be aware that potting, sealing or adhesive compounds can produce chemical reactions in the CeraDiode ceramic that will degrade its electrical characteristics and reduce its lifetime.
- Make sure an electrode is not scratched before, during or after the mounting process.
- Make sure contacts and housings used for assembly with CeraDiodes are clean before mounting.
- The surface temperature of an operating CeraDiode can be higher. Ensure that adjacent components are placed at a sufficient distance from a CeraDiode to allow proper cooling.
- Avoid contamination of the CeraDiode surface during processing.
- Only CeraDiodes with an Ni barrier termination are approved for lead-free soldering.

Soldering

- Complete removal of flux is recommended to avoid surface contamination that can result in an instable and/or high leakage current.
- Use resin-type or non-activated flux.
- Bear in mind that insufficient preheating may cause ceramic cracks.
- Rapid cooling by dipping in solvent is not recommended, otherwise a component may crack.

Standard series

<u>SMD</u>

EPCOS

Operation

- Use CeraDiodes only within the specified operating temperature range.
- Use CeraDiodes only within specified voltage and current ranges.
- Environmental conditions must not harm a CeraDiode. Only use them in normal atmospheric conditions. Reducing the atmosphere (e.g. hydrogen or nitrogen atmosphere) is prohibited.
- Prevent a CeraDiode from contacting liquids and solvents. Make sure that no water enters a CeraDiode (e.g. through plug terminals).
- Avoid dewing and condensation.
- EPCOS CeraDiodes are designed for encased applications. Under all circumstances avoid exposure to:
 - direct sunlight
 - rain or condensation
 - steam, saline spray
 - corrosive gases
 - atmosphere with reduced oxygen content
- EPCOS CeraDiodes are not suitable for switching applications or voltage stabilization where static power dissipation is required.
- CeraDiodes are designed for ESD protection only.

This listing does not claim to be complete, it merely reflects the experience of EPCOS AG.

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- 1. Some parts of this publication contain statements about the suitability of our products for certain areas of application. These statements are based on our knowledge of typical requirements that are often placed on our products in the areas of application concerned. We nevertheless expressly point out that such statements cannot be regarded as binding statements about the suitability of our products for a particular customer application. As a rule, EPCOS is either unfamiliar with individual customer applications or less familiar with them than the customers themselves. For these reasons, it is always ultimately incumbent on the customer to check and decide whether an EPCOS product with the properties described in the product specification is suitable for use in a particular customer application.
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